## NSN 5961-01-318-0122

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-318-0122 **Inclosure Material:** Glass or plastic **Overall Length:** Between 0.185 inches and 0.260 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.100 inches and 0.120 inches **End Application:** General purpose electronic test equipment gpete, calibration standards equipment, strategic weapon systems (poseidon & trident) **Mounting Method: Terminal Criticality Code Justification: Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20.0 reverse voltage, instantaneous and 0.55 forward voltage, dc **Current Rating Per Characteristic:** 1.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Weapom system essential; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0